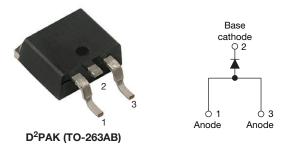
ISHA www.vishay.com

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High Voltage Surface Mount Input Rectifier Diode, 10 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	10 A						
V _R	1200 V						
V _F at I _F	1.1 V						
I _{FSM}	160 A						
T _J max.	150 °C						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single						

FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- · Glass passivated pellet chip junction
- AEC-Q101 gualified
- Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Input rectification
- · On-board and off-board EV / HEV battery chargers

DESCRIPTION

The VS-10ETS12SLHM3 rectifier series has been optimized for very low forward voltage drop, with moderate leakage.

OUTPUT CURRENT IN TYPICAL APPLICATIONS									
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS						
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	12.0	16.0	А						

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Sinusoidal waveform	10	А						
V _{RRM}		1200	V						
I _{FSM}		160	A						
V _F	10 A, T _J = 25 °C	1.1	V						
TJ		-40 to +150	°C						

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA
VS-10ETS12SLHM3	1200	1300	0.5



HALOGEN

FREE

VS-10ETS12SLHM3



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ABSOLUTE MAXIMUM RATING	S			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	$T_C = 105$ °C, 180° conduction half sine wave	10	
Maximum peak one cycle		10 ms sine pulse, rated V_{RRM} applied	135	А
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	160	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	91	A ² s
Maximum r-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	130	A-2
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1290	A²√s

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST (VALUES	UNITS				
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C	1.1	V				
Forward slope resistance	r _t	T.I = 150 °C	20	mΩ				
Threshold voltage	V _{F(TO)}	IJ = 150 C		0.82	V			
Maximum rayaraa laakaga aurrant	1	T _J = 25 °C	V_{-} roted V_{-}	0.05	mA			
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = rated V _{RRM}	0.50	ШA			

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +150	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	2.5	°C/W				
Maximum thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		62	0/10				
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Marking device		Case style D ² PAK (TO-263AB)	10ETS	12SH				

Note

 $^{(1)}$ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W.



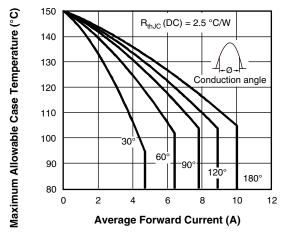


Fig. 1 - Current Rating Characteristics

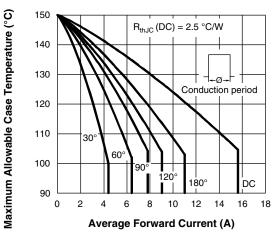


Fig. 2 - Current Rating Characteristics

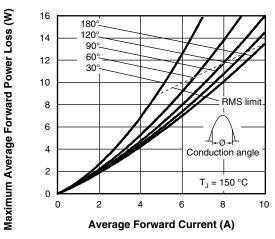
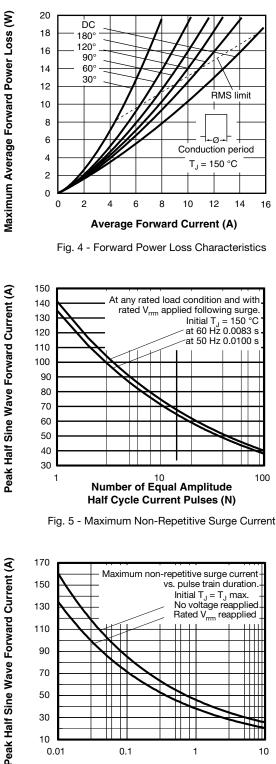


Fig. 3 - Forward Power Loss Characteristics

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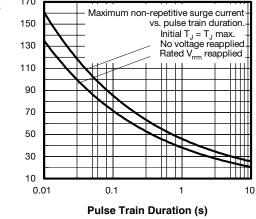


Fig. 6 - Maximum Non-Repetitive Surge Current

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Document Number: 96484

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VS-10ETS12SLHM3

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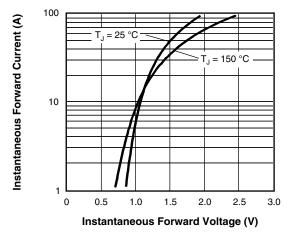


Fig. 7 - Forward Voltage Drop Characteristics

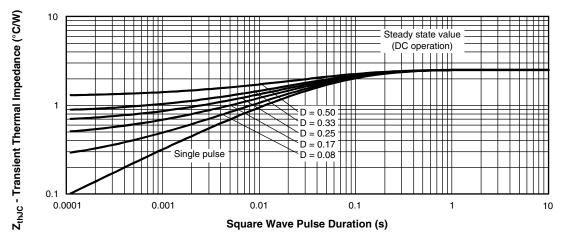


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



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ORDERING INFORMATION TABLE

Device code	VS-	10	Е	т	S	12	S	L	н	М3
	1	2	3	4	5	6	7	8	9	10
	1	- Visl	hay Sen	nicondul	tors proc	duct				
	2 -	Cur	rent rati	ng (10 =	= 10 A)					
	3 -	Circ	uit conf	iguratior	ו:					
		E	E = single							
	4 -	Pac	Package:							
		Т	= D ² PA	K (TO-2	63AB)					
	5 -		e of silio	-	,					
				ard reco	overy ree	ctifier				
	6 -			le x 100	-			12 = 12	00 V	
	7 -			mounta		•	L			
	8 .					ted) fo	r diffore	nt orien	tation	
			L = tape and reel (left oriented), for different orientation, contact factory							
	9			- 101 qua	alified					
	10			ntal digit						
				-						
		M3	= halog	en-free,	RoHS-	complia	int, and	termina	ations le	ad (Pb)-

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-10ETS12SLHM3	800	800	13" diameter reel				

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96317					

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES		MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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